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Substitute for form 1449B/PTO INFORMATION DISCLOSURE STATEMENT BY APPLICANT Date Submitted: July 10, 2006 <i>(use as many sheets as necessary)</i>				Complete if Known	
Application Number		Unassigned			
Filing Date		12/28/2004			
First Named Inventor		Kazuya UEJIMA			
Group Art Unit		Unassigned 4136			
Examiner Name		Unassigned Duy T Nguyen			
Attorney Docket Number		065686-0163			

U.S. PATENT DOCUMENTS						
Examiner Initials*	Cite No. ¹	U.S. Patent Document		Name of Patentee or Applicant of Cited Document	Date of Publication of Cited Document MM-DD-YYYY	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
		Number	Kind Code ² (if known)			
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Examiner Initials*	Cite No. ¹	Foreign Patent Document			Name of Patentee or Applicant of Cited Documents	Date of Publication of Cited Document MM-DD-YYYY	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear	T ⁶
		Office ³	Number ⁴	Kind Code ⁵ (if known)				
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NON PATENT LITERATURE DOCUMENTS				
Examiner Initials*	Cite No. ¹	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.) date, page(s), volume-issue number(s), publisher, city and/or country where published.	T ⁶	
/D.N./	A12	J.L. HOYT et al., "Strained Silicon MOSFET Technology," IEDM 2002, pp. 23-26.		
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/D.N./	A14	H.C. -H. WANG et al., "Substrate-Strained Silicon Technology: Process Integration," IEDM 2003, pp. 61-64.		

Examiner Signature	/Duy Nguyen/	Date Considered	10/29/2008
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¹ Unique citation designation number. ² See attached Kinds of U.S. Patent Documents. ³ Enter Office that issued the document, by the two-letter code (WIPO Standard ST.3). ⁴ For Japanese patent documents, the indication of the year of the reign of the Emperor must precede the serial number of the patent document. ⁵ Kind of document by the appropriate symbols as indicated on the document under WIPO Standard ST. 16 if possible. ⁶ Applicant is to place a check mark here if English language Translation is attached.

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